TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX541F,TC74LCX541FT,TC74LCX541FK

Low-Voltage Octal Bus Buffer with 5-V Tolerant Inputs and Outputs

The TC74LCX541 is a high-performance CMOS octal bus buffer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

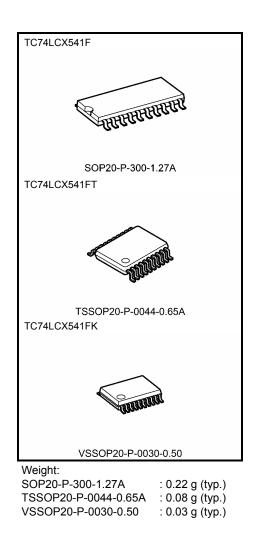
The device is designed for low-voltage $(3.3 \text{ V}) \text{ V}_{CC}$ applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

The TC74LCX541 is a non-inverting 3-state buffer having two active-low output enables. When either $\overline{\text{OE1}}$ or $\overline{\text{OE2}}$ are high, the terminal outputs are in the high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

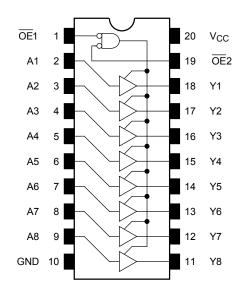
Features

- Low-voltage operation: $V_{CC} = 2.0$ to 3.6 V
- High-speed operation: $t_{pd} = 6.5 \text{ ns} \text{ (max)} (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA} (\text{min}) (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: -500 mA
- Available in JEITA SOP, TSSOP and VSSOP (US)
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 541 type



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Pin Assignment (top view)



Truth Table

	Inputs					
OE1	OE2	An	Outputs			
н	Х	х	Z			
Х	Н	Х	Z			
L	L	Н	Н			
L	L	L	L			

X: Don't care

Z: High impedance

IEC Logic Symbol

$\frac{\overline{OE}_1}{\overline{OE}_2} \frac{(1)}{(19)}$	&	EN	
A1 (2) A2 (3) A3 (4) A3 (5) A4 (6) A5 (7) A6 (8) A7 (9) A8 (9)			(18) Y1 (17) Y2 (16) Y3 (15) Y4 (14) Y5 (13) Y6 (12) Y7 (11) Y8

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	–0.5 to 7.0	V
DC input voltage	VIN	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
		(Note 3)	
Input diode current	I _{IK}	-50	mA
Output diode current	I _{OK}	±50 (Note 4)	mA
DC output current	IOUT	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	–65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 2: Output in OFF state
- Note 3: High or low state. IOUT absolute maximum rating must be observed.
- Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	2.0 to 3.6	V
Fower supply voltage	VCC	1.5 to 3.6 (Note 2)	v
Input voltage	VIN	0 to 5.5	V
Output voltage	Vour	0 to 5.5 (Note 3)	V
Output voltage	V _{OUT}	0 to V_{CC} (Note 4)	v
Output current	IOH/IOI	±24 (Note 5)	mA
Output current	'OH''OL	±12 (Note 6)	ША
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

- Note 3: Output in OFF state
- Note 4: High or low state
- Note 5: $V_{CC} = 3.0$ to 3.6 V
- Note 6: $V_{CC} = 2.7$ to 3.0 V
- Note 7: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C)

Character	ristics	Symbol	Test C	Condition	V _{CC} (V)	Min	Max	Unit
	H-level	VIH		_	2.7 to 3.6	2.0		
Input voltage	L-level	VIL			2.7 to 3.6	_	0.8	V
				$I_{OH} = -100 \ \mu A$	2.7 to 3.6	V _{CC} - 0.2	_	
	H-level	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -12 \text{ mA}$	2.7	2.2		
		-		I _{OH} = -18 mA	3.0	2.4	_	
Output voltage				$I_{OH} = -24 \text{ mA}$	3.0	2.2		V
			$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 100 \ \mu A$	2.7 to 3.6	_	0.2	-
	L-level	Vol		$I_{OL} = 12 \text{ mA}$	2.7	_	0.4	
	L-IEVEI	VOL		I _{OL} = 16 mA	3.0	_	0.4	
				$I_{OL} = 24 \text{ mA}$	3.0	_	0.55	
Input leakage curre	nt	I _{IN}	$V_{IN} = 0$ to 5.5 V		2.7 to 3.6	_	±5.0	μA
3-state output off-st	ate current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		2.7 to 3.6		±5.0	μΑ
Power off leakage of	urrent	IOFF	$V_{IN}/V_{OUT} = 5.5 V$		0		10.0	μΑ
Quieseent augely aurrent			V _{IN} = V _{CC} or GND		2.7 to 3.6		10.0	
Quiescent supply ct	cent supply current $I_{CC} = \frac{1}{V_{IN}/V_{OUT}} = 3.6 \text{ to } 5.5 \text{ V}$		V	2.7 to 3.6		±10.0	μA	
Increase in I _{CC} per	input	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6		500	

AC Characteristics (Ta = -40 to 85°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	7.5	ns
Topagation delay time	t _{pHL}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	6.5	
Output enable time	t _{pZL}	Figure 1, Figure 3	2.7	—	9.5	ns
	t _{pZH}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	8.5	
Output disable time	t _{pLZ}	Figure 1, Figure 3	2.7	_	8.5	ns
	t _{pHZ}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	7.5	115
Output to output skew	t _{osLH}	(Note) -	2.7	_	_	20
	t _{osHL}		$\textbf{3.3}\pm\textbf{0.3}$	_	1.0	ns

Note: Parameter guaranteed by design.

 $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500 \Omega$)

Characteristics		Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic	V _{OL}	V _{OLP}	$V_{IH} = 3.3 \text{ V}, \ V_{IL} = 0 \text{ V}$	3.3	0.8	V
Quiet output minimum dynamic	V _{OL}	V _{OLV}	$V_{IH} = 3.3 \text{ V}, \text{ V}_{IL} = 0 \text{ V}$	3.3	0.8	V

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Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	CIN	_	3.3	7	pF
Output capacitance	C _{OUT}	_	3.3	8	pF
Power dissipation capacitance	CPD	f _{IN} = 10 MHz (Note	3.3	40	pF

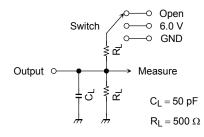
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per bit)

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AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND



AC Waveform

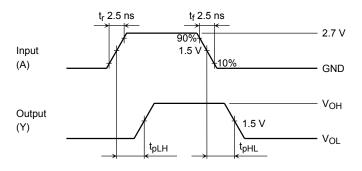


Figure 2 t_{pLH}, t_{pHL}

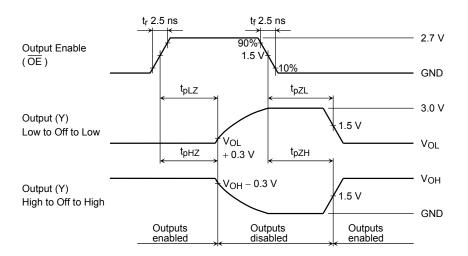
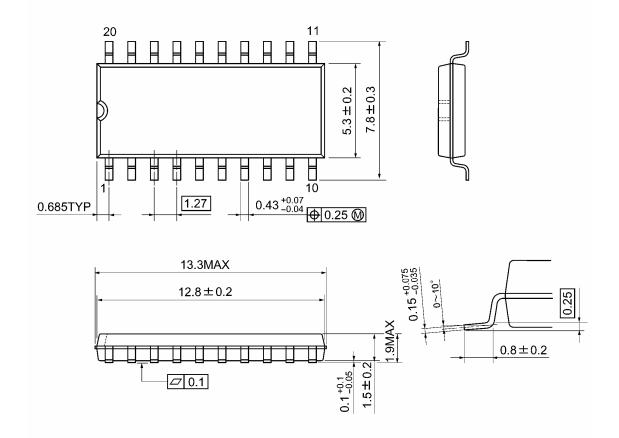


Figure 3 $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$

Package Dimensions

SOP20-P-300-1.27A

Unit: mm



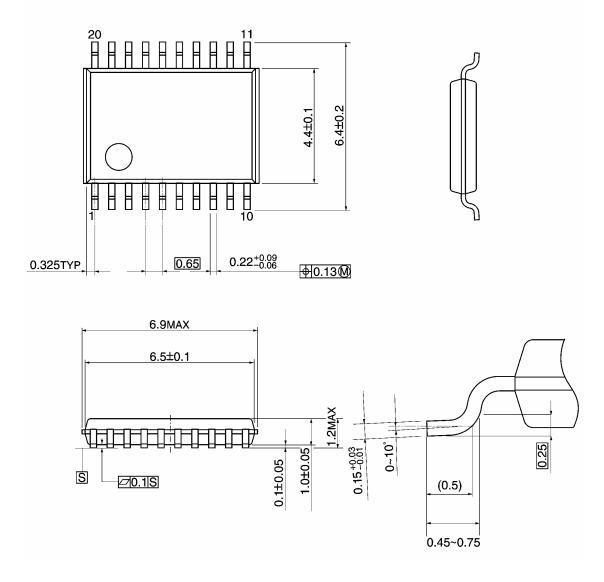
Weight: 0.22 g (typ.)

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Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm



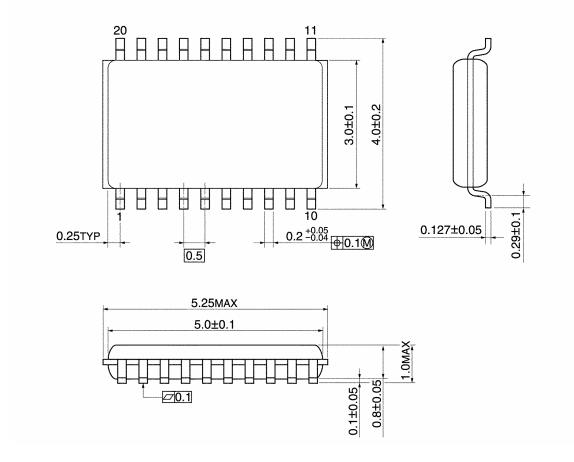
Weight: 0.08 g (typ.)

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Package Dimensions

VSSOP20-P-0030-0.50

Unit: mm



Weight: 0.03 g (typ.)

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20070701-EN GENERAL

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